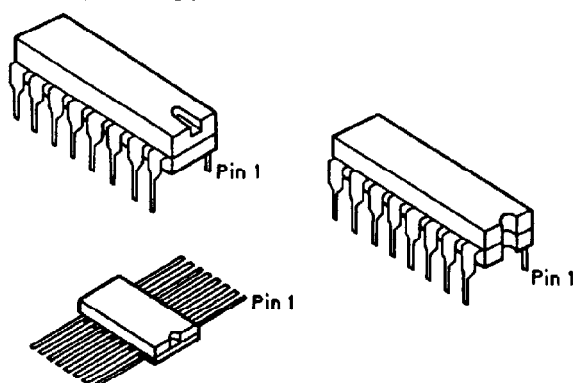


BRITISH STANDARDS INSTITUTION 2 PARK STREET, LONDON. W1A 2BS	BS CECC 90103 - 062 ISSUE 1 JULY 1981
Specification available from:- AS SHOWN IN PD 9002 AND CECC 00 200 AND	 Page 1 of 18 pages
ELECTRONIC COMPONENTS OF ASSESSED QUALITY DETAIL SPECIFICATION IN ACCORDANCE WITH: BS CECC 90 000 : 1976 BS CECC 90 100 : 1977	MANUFACTURERS TYPE NUMBER 54LS151 64LS151 74LS151 84LS151 SEE PD 9002 AND CECC 00 200 For ordering information see clause 1
Outline not to scale: Isometric projection Marking information see clause 1  Refer to IEC 191-1-50a (type A50C) Dual-in-Line (plastic or ceramic) refer to Appendix A1.3 Flatpack (metal or ceramic)	DATA SELECTOR/MULTIPLEXERS TYPICAL CONSTRUCTION SILICON MONOLITHIC BIPOLAR TTL-LOW-POWER SCHOTTKY ASSESSMENT LEVELS R, S, T AND V

1. Type description

- 1.1 Truth table (see page 2)
 (each gate)

Refer to Qualified Products List PD 9002 and/or CECC 00 200
 for details of manufacturers approved to this specification

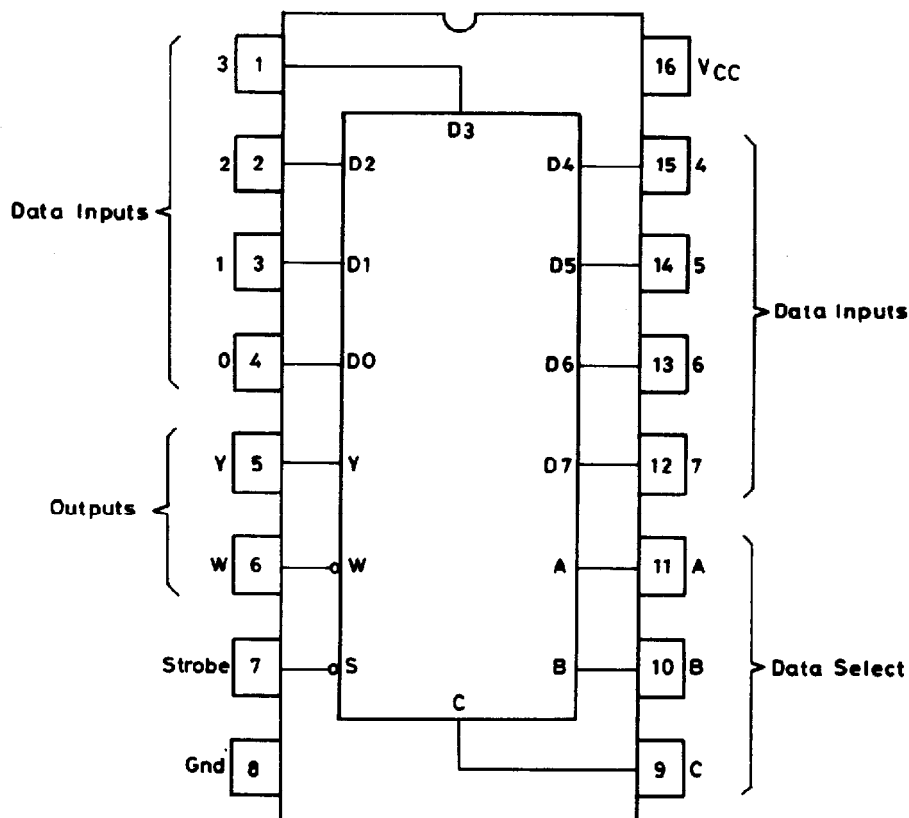
1.1 Truth table (each gate) (contd)

INPUTS				OUTPUTS	
A	B	C	STROBE	W	Y
X	X	X	H	$\overline{H}$	L
L	L	L	L	$\overline{D0}$	D0
H	L	L	L	$\overline{D1}$	D1
L	H	L	L	$\overline{D2}$	D2
H	H	L	L	$\overline{D3}$	D3
L	L	H	L	$\overline{D4}$	D4
H	L	H	L	$\overline{D5}$	D5
L	H	H	L	$\overline{D6}$	D6
H	H	H	L	$\overline{D7}$	D7

H = High level
L = Low level
X = Logic level irrelevant

1.2 Terminal identification, type designation and marking

1.2.1 Terminal identification



Data selector/multiplexers

1.2.2 Type Designation

TEMPERATURE RANGE	PACKAGE		
	Ceramic Dual-in-Line	Plastic Dual-in-Line	Ceramic Flatpack
0 + 70	74LS151J	N	W
-25 + 85	84LS151J		
-40 + 85	64LS151J		
-55 +125	54LS151J		

1.2.3 Marking

Each integrated circuit shall bear the following markings:

- (1) Terminal identification
- (2) Type designation
- (3) Date code
- (4) Factory identification code (unless derived from trademark)
- (5) Manufacturers trade name or mark
- (6) Mark of conformity (unless a certificate of conformity is used)

1.3 Ordering information

Orders for these integrated circuits shall contain the following minimum information:

Manufacturers integrated circuit type designation screening procedures and assessment level as detailed to this CECC specification number.

(For details of screening procedures see Appendix A1.1)

2. Limiting conditions of use (not for inspection purposes)

2.1	Maximum continuous supply voltage	V_{CC}						-0,5V +7,0V
2.2	Maximum input voltages							
2.2.1	Maximum input voltage	V_I						-0,5V +7,0V
2.2.2	Maximum input voltage between multiple emitter transistor inputs	V_{II}						+5,5V
2.3	Minimum and maximum operating ambient temperatures	$T_{amb}(^{\circ}C)$	min. max.	-55 +125	-40 +85	0 +70	-25 +85	
2.4	Minimum and maximum storage temperatures	$T_{stg}(^{\circ}C)$	min. max.	-65 +150	(All types)			

3. Recommended operating conditions and associated characteristics (not for inspection purposes)

3.1 Recommended operating conditions.

These apply over the operating ambient temperature range unless otherwise stated.

Description	Symbol	Type	Value	Unit
Positive supply voltage range	V_{CC}	54LS 64/74/84LS	4,5 - 5,5 4,75 - 5,25	V V
Minimum value of High level input voltage	V_{IHB}	All types	2,0	V
Maximum value of High level input voltage	V_{IHA}	All types	5,5	V
Minimum value of Low level input voltage	V_{ILB}	All types	-0,3	V
Maximum value of Low level input voltage	V_{ILA}	54LS 64/74/84LS	0,7 0,8	V V
Maximum value of Low level output current for each output	I_{OLA}	54LS 64/74/84LS	4,0 8,0	mA mA
Maximum value of output current for each output at V_{OH}	I_{OHA}	All types	-400,0	μA

3.2 Associated characteristics

3.2.1 Minimum and maximum values are given for the worst case operation over the ambient temperature range, except for those conditions marked with an asterisk (*)

	54LS	64LS	74LS	84LS	
T_{amb} min.	-55	-40	0	-25	°C
T_{amb} max.	+125	+85	+70	+85	
V_{CC} min.	4,5	4,75			V
V_{CC} max.	5,5	5,25			

3.2.2

Characteristics	Conditions	$V_{CC}(V)$	Symbol	Min.	Max.	Unit
Total supply current with High level output	$V_{IN} = 4,5V$ All inputs All outputs open circuit	V_{CC} max.	I_{CC}	-	10,0	mA
High level input current	$V_{IH(1)} = 7,0V$	V_{CC} max.	$I_{IH(1)}$	-	100,0	μA
	$V_{IH(2)} = 2,7V$	V_{CC} max.	$I_{IH(2)}$	-	20,0	μA
Low level input current	$V_{IL} = 0,4V$	V_{CC} max.	$-I_{IL}$	-	0,4	mA
Input clamping voltage	$-I_{IC} = 18,0mA$	V_{CC} min.	$-V_{ICA}$	-	1,5	V
Output voltage 54LS 64/74/84LS All types 64/74/84LS	$I_{OH} = 400,0\mu A$	V_{CC} min.	V_{OH}	2,5	-	V
	$I_{OH} = 400,0\mu A$		V_{OH}	2,7	-	V
	$I_{OL(1)} = 4,0mA$ (1)		$V_{OL(1)}$	-	0,4	V
	$I_{OL(2)} = 8,0mA$ (2)		$V_{OL(2)}$	-	0,5	V
Output short circuit current	$V_O = 0V$ (3) $V_{IL} = 0V$ or $4,5V$	V_{CC} max.	$-I_{OS}$	15,0	130,0	mA
Propagation time All types	$T_{amb} = 25^\circ C^*$ test conditions as in Sub-group A5	5,0V				
Low to High level						
From A, B or C (4 levels) to Y			t_{PLH}	-	43,0	ns
From A, B or C (3 levels) to W			t_{PLH}	-	23,0	ns
From Strobe to Y			t_{PLH}	-	42,0	ns
From Strobe to W			t_{PLH}	-	24,0	ns
Any D to Y			t_{PLH}	-	32,0	ns
Any D to W			t_{PLH}	-	21,0	ns
High to Low level						
From A, B or C (4 levels) to Y			t_{PHL}	-	30,0	ns
From A, B or C (4 levels) to W			t_{PHL}	-	32,0	ns

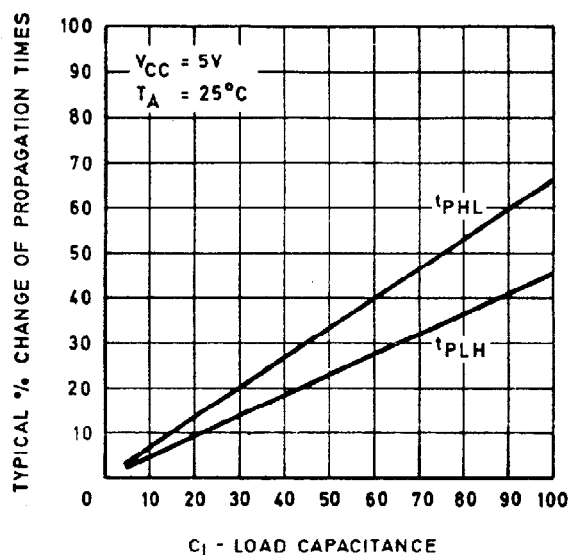
- (1) Fan out = 10, (2) Fan out = 20,
(3) Only one output at a time, duration $t \leq 1$ sec
*See clause 3 of this specification

3.2.2 (contd)

Characteristics	Conditions	$V_{CC}(V)$	Symbol	Min.	Max.	Unit
High to Low level						
From Strobe to Y			t_{PHL}	-	32,0	ns
From Strobe to W			t_{PHL}	-	30,0	ns
Any D to Y			t_{PHL}	-	26,0	ns
Any D to W			t_{PHL}	-	20,0	ns

3.3 Supplementary information

3.3.1 Change of typical propagation time with output loading



Propagation times Vs. load capacitance

3.3.2 DC noise margin

$$\text{Low level } (V_{ILA} - V_{OLA}) = V_{NL}$$

$$\text{High level } (V_{IHB} - V_{OHB}) = V_{NH}$$